

Attorney Docket: 381NP/50378
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: SHINYA SATOU ET AL.
Serial No.: 09/936,480 Group Art Unit: 2855
Filed: DECEMBER 26, 2001 Examiner: MARISSA L. FERGUSON
Title: SEMICONDUCTOR PRESSURE SENSOR AND PRESSURE
DETECTOR

REPLY UNDER 37 C.F.R. §1.111

Commissioner for Patents
Washington, D.C. 20231

Sir:

The following amendments and remarks are respectfully submitted in response to the Office Action dated October 2, 2002.

IN THE CLAIMS:

Please amend claims 1-9 as follows:

(A copy of the marked-up version of the amended claims are attached to this Reply).

1. (Amended) A semiconductor pressure sensor, comprising:
a substrate,
a diaphragm formed on said substrate by a sacrificial layer etching method, and